OMRON

MOS FET Relays

G3VM-41GR3

New MOS FET Relays with Low Output Capacitance and ON Resistance ($C \times R = 15 pF \cdot \Omega$) in a 40-V Load Voltage Model.

- Output capacitance of 0.6 pF (typical) allows high-frequency applications.
- Leakage current of 1.0 nA max. when output relay is onen

RoHS compliant

/ Refer to "Common Precautions".

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Note: The actual product is marked differently from the image

shown here.

■ Application Examples

- Semiconductor inspection tools
- Measurement devices
- · Broadband systems
- Data loggers

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	40 VAC	G3VM-41GR3	100	
	terminals		G3VM-41GR3(TR)		2,500

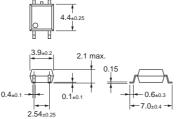
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-41GR3



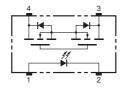
Note: The actual product is marked differently from the image shown here.



Weight: 0.1 c

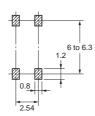
■ Terminal Arrangement/Internal Connections (Top View)

G3VM-41GR3



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-41GR3



Note:

■ Absolute Maximum Ratings (Ta = 25°C)

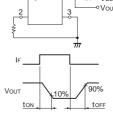
ltem		Symbol	Rating	Rating Unit Measuremen	
Input	LED forward current	I _F	50	mA	
į	Repetitive peak LED forward current	I _{FP}	1	А	100 μs pulses, 100 pps
į	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	V_R	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	V _{OFF}	40	V	
	Continuous load current	Io	80	mA	
	ON current reduction rate	Δ I _{ON} /°C	-0.8	mA/°C	Ta ≥ 25°C
	Connection temperature	Tj	125	°C	
	ric strength between input and (See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min
Operating temperature		Ta	-20 to +85	°C	With no icing or condensation
Storage	e temperature	T _{stg}	-40 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

	ltem	Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage	V_{F}	1.0	1.15	1.3	V	I _F = 10 mA	
	Reverse current	I _R			10	μΑ	V _R = 5 V	
	Capacity between terminals	C _T		15		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I _{FT}			4	mA	I _O = 100 mA	
Output	Maximum resistance with output ON	R _{ON}		25	35	Ω	I _F = 5 mA, I _O = 80 mA, t < 1 s	
	Current leakage when the relay is open	I _{LEAK}			1.0	nA	V _{OFF} = 20 V, Ta = 50°C	
	Capacity between terminals	C _{OFF}		0.6	1.4	pF	V = 0, f = 100 MHz, t < 1 s	
Capacity	between I/O terminals	C _{I-O}		8.0		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		R _{I-O}	1,000			ΜΩ	V _{I-O} = 500 VDC, RoH ≤ 60%	
Turn-ON time		tON			0.5	ms	$I_F = 10 \text{ mA}, R_L = 200 \Omega, V_{DD} = 20 \text{ V (See note 2.)}$	
Turn-OFF time		tOFF			0.5	ms		

Note: 2. Turn-ON and Turn-OFF Times



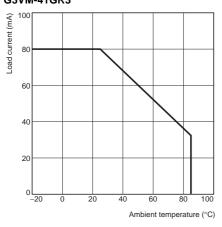
■Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V_{DD}			32	V
Operating LED forward current	I _F	10		30	mA
Continuous load current	Io			80	mA
Operating temperature	Ta	25		60	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-41GR3



■ Safety Precautions

Refer to "Common Precautions" for all G3VM models.